

RJF0626JNS

N Channel Thermal FET Power Switching R07DS1559EJ0100 Rev.1.00 May 28, 2024

Datasheet

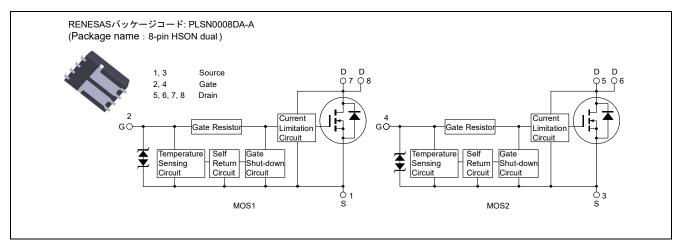
Description

This FET has the over temperature shut-down capability sensing to the junction temperature. This FET has the built-in over temperature shut-down circuit in the gate area. And this circuit operation to shut-down the gate voltage in case of high junction temperature like applying over power consumption, over current etc..

Features

- Logic level operation. (4 V Gate drive).
- Built-in the over temperature shut-down circuit and current limitation circuit.
- High endurance capability against to the short circuit.
- Temperature hysteresis type.
- High density mounting
- Built-in the current limitation circuit.
- Power supply voltage applies 12 V and 24 V.
- AEC-Q101Rev-E compliant.

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	VDSS	60	V
Gate to source voltage	V _{GSS}	16	V
Gate to source voltage	V _{GSS}	-2.5	V
Drain current	D Note4	7	А
Body-drain diode reverse drain current	I _{DR}	7	А
Avalanche current	AP Note 3	7	А
Avalanche energy	EAR Note 3	14.7	mJ
Channel dissipation	Pch Note 1	30	W
Channel dissipation	Pch Note 2	1	W
Channel temperature	Tch	150	۵°
Storage temperature	Tstg	–55 to +150	۵°

Notes: 1. Tch = 25° C, 1 Drive operation.

2. 1 Drive operation : When using the glass epoxy board (FR4 $40 \times 40 \times 1.6$ mm)

3. Tch = 25°C, Rg \geq 50 Ω

4. It provides by the current limitation lower bound value.



Typical Operation Characteristics

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input voltage	VIH	3.5		_	V	
	VIL	_		1.2	V	
Input current	I _{IH1}			100	μA	Vi = 8 V, V _{DS} = 0
(Gate non shut down)	I _{IH2}	_		50	μA	Vi = 3.5 V, V _{DS} = 0
	IIL	_		1	μA	Vi = 1.2 V, V _{DS} = 0
Input current	I _{IH(sd)1}	_	0.8	_	mA	Vi = 8 V, V _{DS} = 0
(Gate shut down)	I _{IH(sd)2}	_	0.35	_	mA	Vi = 3.5 V, V _{DS} = 0
Shut down temperature	Tsd	_	175	_	°C	Channel temperature
Return temperature	Thr		120		°C	Channel temperature
Gate operation voltage	Vop	3.5		12	V	
Drain current (Current limitation value)	I _{D limt}	7	_	_	Α	Vi = 5 V, V _{DS} = 10 V ^{Note 5}

Notes: 5. Pulse test

Electrical Characteristics

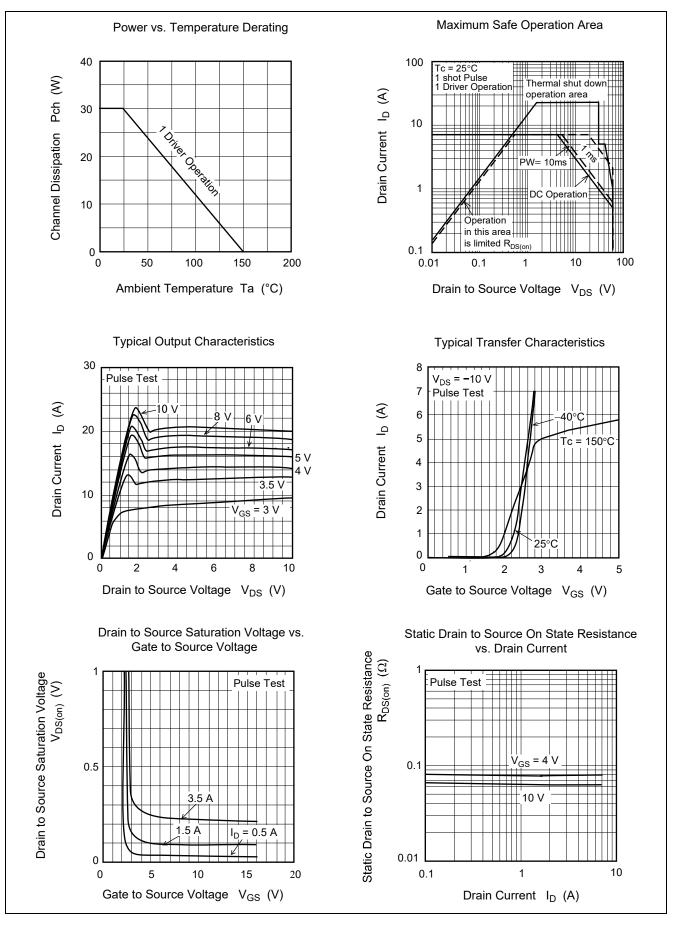
						$(Ta = 25^{\circ}C)$
ltem	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain current	I _{D1}	_	_	10	mA	V _{GS} = 1.2 V, V _{DS} = 10 V
	I _{D2}	7	_	_	Α	V _{GS} = 5 V, V _{DS} = 10 V ^{Note6}
Drain to source breakdown	V _{(BR)DSS}	60		_	V	I _D = 10 mA, V _{GS} = 0
voltage						
Gate to source breakdown	V _(BR) GSS	16			V	I _G = 800 μA, V _{DS} = 0
voltage	V _(BR) GSS	-2.5		_	V	I _G = -100 μA, V _{DS} = 0
Gate to source leak current	lgss	_		100	μA	$V_{GS} = 8 V, V_{DS} = 0$
	lgss	_	_	50	μA	V _{GS} = 3.5 V, V _{DS} = 0
	lgss	_	—	1	μA	V _{GS} = 1.2 V, V _{DS} = 0
	lgss	_		-100	μA	$V_{GS} = -2.4 V, V_{DS} = 0$
Input current (shut down)	I _{GS(OP)}	_	0.8	_	mA	$V_{GS} = 8 V, V_{DS} = 0$
	I _{GS(OP)}	_	0.35	_	mA	V _{GS} = 3.5 V, V _{DS} = 0
Zero gate voltage drain current	IDSS	_		10	μA	V _{DS} = 60 V, V _{GS} = 0
Gate to source cutoff voltage	V _{GS(off)}	1.1	_	2.1	V	V _{DS} = 10 V, I _D = 1 mA
Static drain to source on state	R _{DS(on)}	_	79.9	100	mΩ	$I_D = 3.5 \text{ A}, V_{GS} = 4 \text{V}^{\text{Note 6}}$
resistance	R _{DS(on)}	—	64.9	80	mΩ	$I_D = 3.5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note 6}}$
Forward transfer admittance	y _{fs}	3.3	10.3		S	I _D = 3.5 A, V _{GS} = 10 V ^{Note 6}
Output capacitance	Coss	_	286	_	pF	$V_{DS} = 10 V, V_{GS} = 0,$
						f = 1MHz
Turn-on delay time	t _{d(on)}	—	3.9	_	μs	$V_{GS} = 5 V, I_{D} = 3.5 A,$
Rise time	tr	—	18.6	_	μs	R _L = 8.5 Ω
Turn-off delay time	t _{d(off)}	—	3.2	_	μs	
Fall time	t _f	—	6.4	_	μs	
Body-drain diode forward voltage	V_{DF}	—	0.8	_	V	I _F = 7 A, V _{GS} = 0
Body-drain diode reverse	trr	_	134		ns	I _F = 7 A, V _{GS} = 0
recovery time						di⊧/dt = 50 A/µs
Over load shut down	t _{os1}	_	0.42	—	ms	V _{GS} = 5 V, V _{DD} = 16 V
operation time Note 7						
Over load shut down	t _{os2}	_	0.27	—	ms	V _{GS} = 5 V, V _{DD} = 24 V
operation time Note 7						

Notes: 6. Pulse test

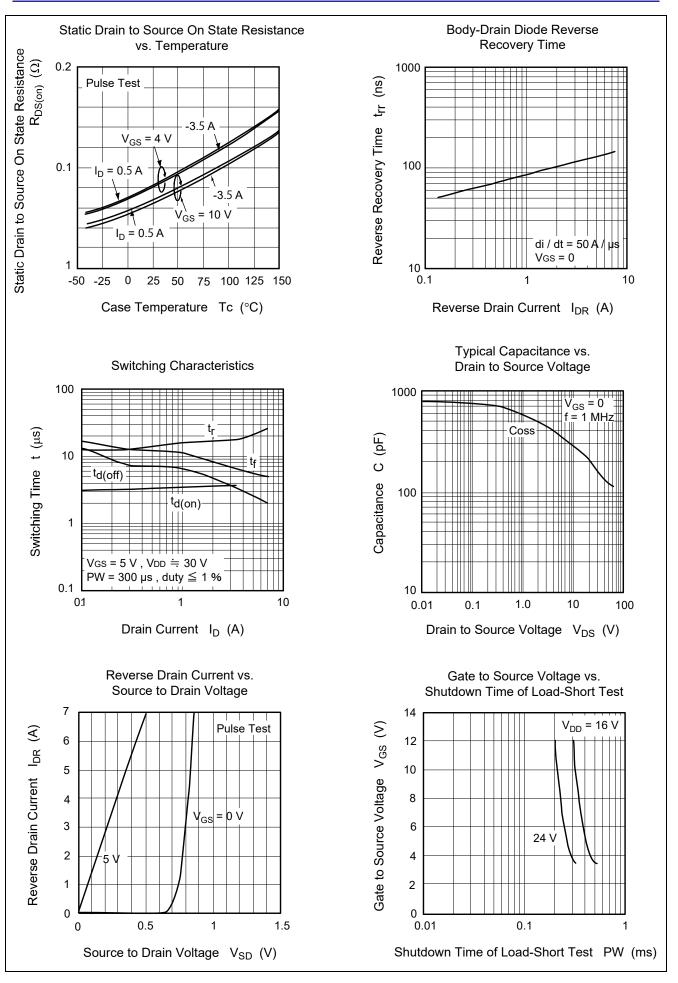
7. Including the junction temperature rise of the over loaded condition.



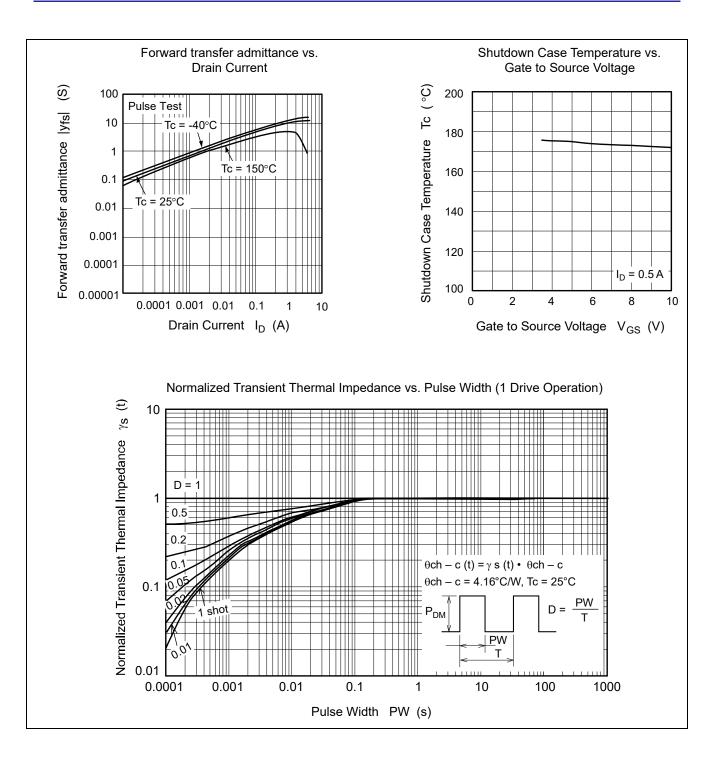
Main Characteristics



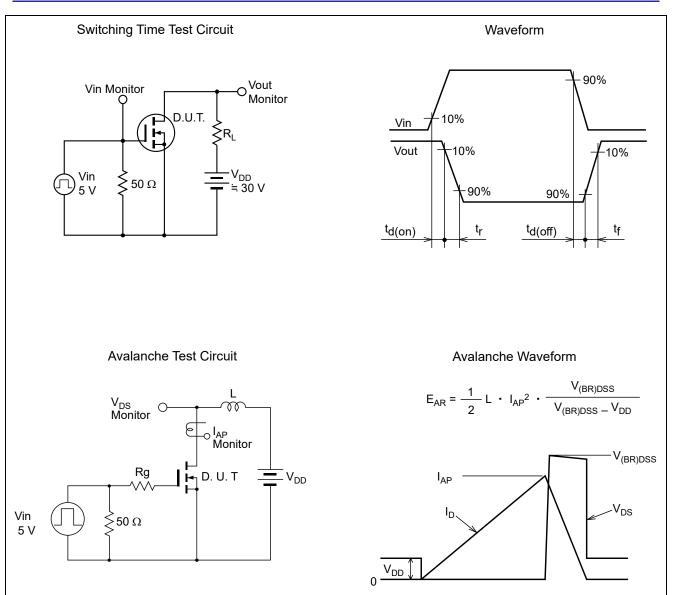








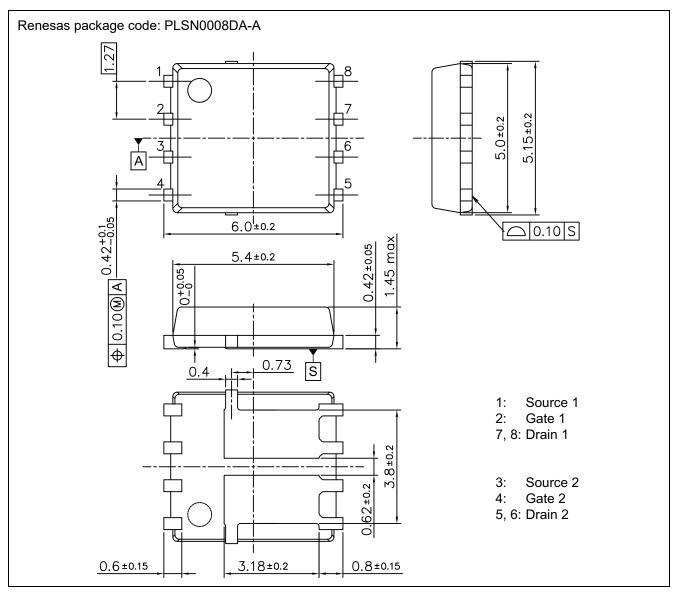






Package Dimensions

8-pin HSON Dual (Mass: 0.12 g TYP.)



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJF0626JNS-00-Q7	2500 pcs/reel	Taping

Note: The symbol of 2nd "-" is occasionally presented as "#".



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